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ΡΛΝ	JIT
	SEMI
	CONDUCTOR

PJQ5850-AU

40V Dual N-Channel Enhancement Mode MOSFET

Voltage

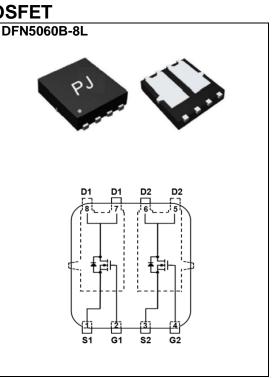
40 V Current

Features

- R_{DS(ON)}, V_{GS}@10V, I_D@8A<33mΩ
- R_{DS(ON)}, V_{GS}@4.5V, I_D@4A<42mΩ
- High switching speed
- Improved dv/dt capability
- Low reverse transfer capacitance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : DFN5060B-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0035 ounces, 0.092 grams



Maximum Ratings and Thermal Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

14 A

PARAMETE	R	SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	40		
Gate-Source Voltage		V _{GS}	<u>+</u> 20	V	
Continuous Drain Current (Note 4)	T _C =25°C		14	А	
	T _c =100°C	l _D	9		
Pulsed Drain Current (Note 1)	T _c =25°C	I _{DM}	56		
Power Dissipation	T _c =25°C	6	14.4	W	
	T _c =100°C	PD	7.2		
Continuous Drain Current (Note 4)	T _A =25°C		5	A	
	T _A =70°C	I _D	4		
Power Dissipation	T _A =25°C	5	2.0		
	T _A =70°C	PD	1.4	W	
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~175	°C	
(Note 4.5)	Junction to Case	R _{θJC}	10.4	°C/W	
Typical Thermal Resistance (Note 4,5)	Junction to Ambient	R _{θJA}	73.5		
Limited only By Maximum Junction Temperature					

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Electrical Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	40	-	-	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250$ uA	1.2	1.8	2.5	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =8A	-	27	33	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =4.5V, I _D =4A	-	35	42	mΩ
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =40V, V _{GS} =0V	-	-	1.0	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 6)		•				
Total Gate Charge	Qg	V_{DS} =20V, I_{D} =5A, V_{GS} =4.5V ^(Note 3)	-	4.4	-	nC
Gate-Source Charge	Q _{gs}		-	1.3	-	
Gate-Drain Charge	Q _{gd}		-	1.7	-	
Input Capacitance	Ciss	V _{DS} =25V, V _{GS} =0V,	-	425	-	
Output Capacitance	Coss		-	48	-	pF
Reverse Transfer Capacitance	Crss	f=1MHZ	-	36	-	-
Turn-On Delay Time	td _(on)		-	9.4	-	
Turn-On Rise Time	tr	$V_{DD}=20V, I_D=1A,$ $V_{GS}=4.5V, R_G=25\Omega$ (Note 3)	-	29	-	
Turn-Off Delay Time	td _(off)		-	21	-	ns
Turn-Off Fall Time	t _f		-	29	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I _S		-	-	14	A
Diode Forward Voltage	V _{SD}	I _S =1A, V _{GS} =0V	-	0.74	1	V

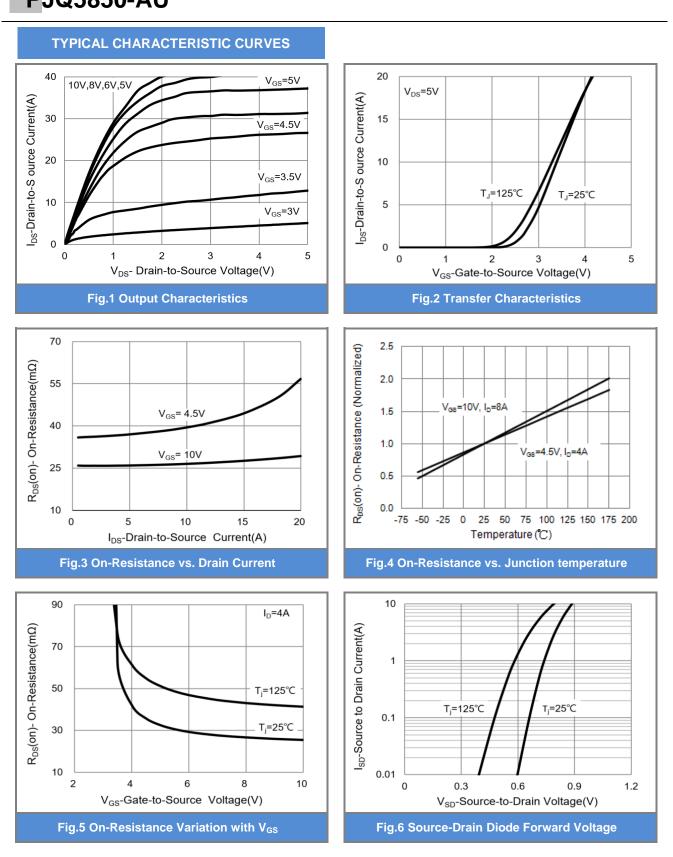
NOTES :

- 1. Pulse width
- 2. Essentially independent of operating temperature typical characteristics.
- Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited.
- 5. $R_{\Theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.

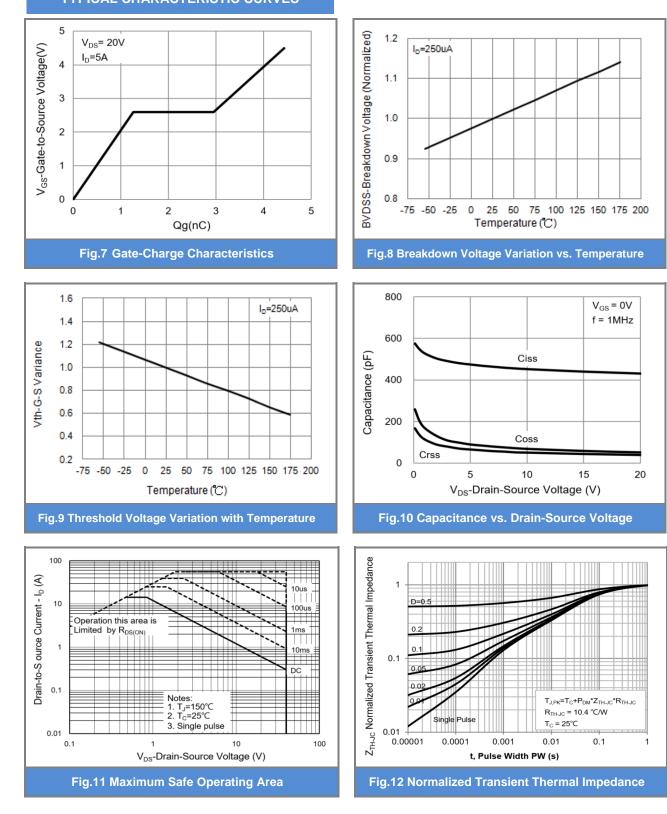
SEMI CONDUCTOR

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PANJ



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TYPICAL CHARACTERISTIC CURVES

CONDUCTOR

SFMI

PJQ5850-AU

PANJ



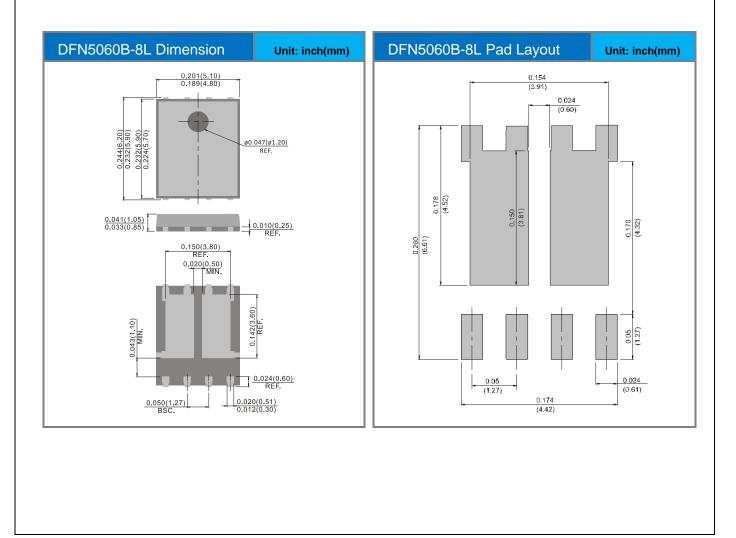


PJQ5850-AU

Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJQ5850-AU_R2_000A	DFN5060B-8L	3000pcs / 13" reel	Q5850	Halogen free

Packaging Information & Mounting Pad Layout





PJQ5850-AU

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